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RFMD(R) To Showcase New Wireless Infrastructure Products and Demonstrate GaN High Power Products At IEEE MTT-S 2007

New Products Expand Reach In Wireless Infrastructure And Military Markets

HONOLULU--(BUSINESS WIRE)--June 4, 2007--RF Micro Devices, Inc. (NASDAQ:RFMD), a global leader in the design and manufacture of high-performance radio systems and solutions for applications that drive mobile communications, today announced it will showcase its new portfolio of GaAs pHEMT low noise amplifiers (LNAs) for wireless infrastructure and provide a demonstration of its GaN high power products for commercial and military applications at the IEEE MTT-S International Microwave Symposium 2007, June 5-7, in Honolulu, Hawaii.

RFMD will showcase the RF386X family of LNAs, which are ideal for the cellular and WiMAX infrastructure markets. These new broadband LNAs offer capabilities from 700MHz to 3800MHz and provide the best-in-class combination of noise and linearity performance, as compared to competing solutions. The RF386X family of LNAs is ideally suited for first stage low noise and linear driver amplification targeting CDMA, PCS, DCS, UMTS, WLAN and WiMAX applications.

In addition, RFMD will host two RF product demonstrations at its trade show booth featuring its first generation 48V GaN transistor technology.

First, RFMD will demonstrate the RF power performance of the RF3934, a 48V GaN 120W power transistor in RFMD's RF393X product family. The RF393X product family offers power performance from 10W to 120W and very wide tunable bandwidth--demonstrating the superior combination of high power and bandwidth offered by GaN technology versus competing GaAs and silicon technologies. The RF393X family offers very high peak efficiency and is suitable for applications such as broadcast, cellular wireless infrastructure, high power radar, aerospace and avionics.

Second, RFMD will demonstrate the RF power performance of the RF3825, a 28V GaN 10W broadband PowerIC in RFMD's RF382X product family. The RF3825 delivers power performance over a frequency range of 225MHz to 1800MHz and is the widest bandwidth product in the RF382X product family. The RF3825 demonstrates 10W power performance over multiple octaves in frequency in a single, size-reduced solution that is more compact than competing solutions. The RF382X family offers very high peak efficiency across the operating bandwidth and is suitable for applications such as 3G cellular infrastructure, military communications, software definable radios (SDRs) and public mobile radio.

Additionally, the Company will showcase its portfolio of highly integrated RF solutions, including RFMD's industry-leading cellular front ends for GSM/GPRS, EDGE, CDMA and WCDMA handsets, its POLARIS™ TOTAL RADIO™ RF solutions for GSM/GPRS and EDGE handsets, its WLAN front ends and its software-based GPS solutions.

RFMD will showcase its industry-leading product portfolio of cellular front end solutions and wireless infrastructure products at the IEEE MTT-S International Microwave Symposium 2007, June 5-7, at the Honolulu Convention Center in Honolulu, Hawaii, in Booth 801.

About RFMD: RF Micro Devices, Inc. (NASDAQ: RFMD) is a global leader in the design and manufacture of high-performance radio systems and solutions for applications that drive mobile communications. RFMD's power amplifiers, transmit modules, cellular transceivers and system-on-chip (SoC) solutions enable worldwide mobility, provide enhanced connectivity and support advanced functionality in current- and next-generation mobile handsets, cellular base stations, wireless local area networks (WLANs) and global positioning systems (GPS). Recognized for its diverse portfolio of state-of-the-art semiconductor technologies and vast RF systems expertise, RFMD is a preferred supplier enabling the world's leading mobile device manufacturers to deliver advanced wireless capabilities that satisfy current and future market demands.

Headquartered in Greensboro, N.C., RFMD is an ISO 9001- and ISO 14001-certified manufacturer with worldwide engineering, design, sales and service facilities. RFMD is traded on the NASDAQ Global Select Market under the symbol RFMD. For more information, please visit RFMD's web site at www.rfmd.com.

This press release includes "forward-looking statements" within the meaning of the safe harbor provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements include, but are not limited to, statements about our plans, objectives, representations and contentions and are not historical facts and typically are identified by use of terms such as "may," "will," "should," "could," "expect," "plan," "anticipate," "believe," "estimate," "predict," "potential," "continue" and similar

words, although some forward-looking statements are expressed differently. You should be aware that the forward-looking statements included herein represent management's current judgment and expectations, but our actual results, events and performance could differ materially from those expressed or implied by forward-looking statements. We do not intend to update any of these forward-looking statements or publicly announce the results of any revisions to these forward-looking statements, other than as is required under the federal securities laws. RF Micro Devices' business is subject to numerous risks and uncertainties, including variability in quarterly operating results, the rate of growth and development of wireless markets, risks associated with the operation of our wafer fabrication facilities, molecular beam epitaxy facility, assembly facility and test and tape and reel facilities, our ability to attract and retain skilled personnel and develop leaders, variability in production yields, our ability to reduce costs and improve gross margins by implementing innovative technologies, our ability to bring new products to market, our ability to adjust production capacity in a timely fashion in response to changes in demand for our products, dependence on a limited number of customers, and dependence on third parties. These and other risks and uncertainties, which are described in more detail in RF Micro Devices' most recent Annual Report on Form 10-K filed with the Securities and Exchange Commission, could cause actual results and developments to be materially different from those expressed or implied by any of these forward-looking statements.

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